NSN 5961-01-264-3342

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-264-3342 **Inclosure Material:** Metal **Overall Length:** 0.700 inches **Overall Height:** 0.440 inches **Overall Diameter:** Between 0.610 inches and 0.640 inches **Electrode Internally-electrically Connected To Case:** Cathode **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 45.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 120.00 amperes forward current, average blank **Capacitance Rating In Picofarads:** 3700.0 Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli

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